









	<h2 style="color: red;">IRFB4229PBF</h2>	
	Hersteller-Teilenummer:	IRFB4229PBF
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	MOSFET N-CH 250V 46A TO-220AB
	Datenblätter:	 IRFB4229PBF.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 32568 pcs Stock Available.
	Liefern von:	Hong Kong
Image may be representation. See specs for product details.	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	IRFB4229PBF
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 250V 46A TO-220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32568 pcs Stock
Serie	HEXFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-40°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	330W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	46A (Tc)
Rds On (Max) @ Id, Vgs	46 mOhm @ 26A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	110nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4560pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube


















































IRFB4229PBF ist neu im Original, Suche IRFB4229PBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFB4229PBF International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IRFB4229PBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IRFB4215PBF International Rectifier (Infineon Technologies) MOSFET N-CH 60V 115A TO-220AB</p>	 <p>IRFB4233 IR/VISHAY IR/VISHAY TO-220AB</p>	 <p>IRFB42N20 IR IRFB42N20 IR</p>	 <p>IRFB42N20DPBF International Rectifier (Infineon Technologies) MOSFET N-CH 200V 44A TO-220AB</p>
 <p>IRFB4228PBF International Rectifier (Infineon Technologies) MOSFET N-CH 150V 83A TO-220AB</p>	 <p>IRFB4227 IR IRFB4227 IR</p>	 <p>IRFB42N20 International Rectifier (Infineon Technologies) MOSFET N-CH 200V 44A TO-220AB</p>	 <p>IRFB4227PBF International Rectifier (Infineon Technologies) MOSFET N-CH 200V 65A TO-220AB</p>

heiße Teile

Mehr

 IRFB3607PBF	 IRFB3607S	 IRFB3806	 IRFB3806PBF	 IRFB38N20D
 IRFB38N20DPBF	 IRFB4019	 IRFB4019PBF	 IRFB4020PBF	 IRFB4103PBF
 IRFB4110	 IRFB4110G	 IRFB4110GPBF	 IRFB4110PBF	 IRFB4110Q
 IRFB4115	 IRFB4115PBF	 IRFB4127	 IRFB4127PBF	 IRFB41N15D
 IRFB41N15DPBF	 IRFB4215PBF	 IRFB4227	 IRFB4227PBF	 IRFB4229
 IRFB4233PBF	 IRFB42N20DPBF	 IRFB4310	 IRFB4310PBF	 IRFB4310Z
 IRFB4310ZG	 IRFB4310ZPBF	 IRFB4321	 IRFB4321PBF	 IRFB4332
 IRFB4332PBF	 IRFB4410	 IRFB4410PBF	 IRFB4410Z	 IRFB4410ZG
 IRFB4410ZGPBF	 IRFB4410ZPBF	 IRFB4411ZPBF	 IRFB4510	 IRFB4510PBF
 IRFB4610	 IRFB4610PBF	 IRFB4615	 IRFB4615PBF	 IRFB4710

Contact us: Info@Y-IC.com

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